

# 1A, 50V - 1000V Glass Passivated High Efficient Rectifier

#### **FEATURES**

- Glass passivated chip junction
- High current capability, Low V<sub>F</sub>
- High reliability
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- TV
- Monitor

#### **MECHANICAL DATA**

- Case: DO-204AL (DO-41)
- Molding compound meets UL 94V-0 flammability rating
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Pure tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.33 g (approximately)

KEY PARAMETERS						
PARAMETER VALUE U						
I <sub>F(AV)</sub>	1	Α				
$V_{RRM}$	50 - 1000	V				
I <sub>FSM</sub>	30	Α				
T <sub>J MAX</sub>	150	°C				
Package	DO-204AL (DO-41)					
Configuration	Single die					





DO-204AL (DO-41)

		HER	HER	HER	HER	HER	HER	HER	HER	
PARAMETER	SYMBOL	101	102	103	104	105	106	107	108	UNIT
		G-K	G-K	G-K	G-K	G-K	G-K	G-K	G-K	
Marking code on the device		HER101 G	HER102 G	HER103 G	HER104 G	HER105 G	HER106 G	HER107 G	HER108 G	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Forward current	$I_{F(AV)}$				1					Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	30							А	
Junction temperature	TJ	- 55 to +150						°C		
Storage temperature	T <sub>STG</sub>	- 55 to +150					°C			



THERMAL PERFORMANCE							
PARAMETER	SYMBOL	LIMIT	UNIT				
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	60	°C/W				
Junction-to-case thermal resistance	$R_{\Theta JC}$	15	°C/W				

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	HER101G-K		V <sub>F</sub>			
	HER102G-K				1.0	
	HER103G-K			-	1.0	V
Forward voltage per diode (1)	HER104G-K	$I_{\rm F} = 1  {\rm A, T_J} = 25  {\rm ^{\circ}C}$				
Forward voltage per diode	HER105G-K	$I_F = IA, I_J = 25 \text{ C}$		-	1.3	V
	HER106G-K					
	HER107G-K			-	1.7	V
	HER108G-K					
Reverse current @ rated V <sub>R</sub> per diode (2)		T <sub>J</sub> = 25°C		-	5	μΑ
		T <sub>J</sub> = 125°C	I <sub>R</sub>	-	150	μΑ
	HER101G-K		CJ			
	HER102G-K					
	HER103G-K	1 MHz, V <sub>R</sub> =4.0V		15	-	pF
Junction capacitance	HER104G-K					
Junction capacitance	HER105G-K					
	HER106G-K					
	HER107G-K			10	-	pF
	HER108G-K					
	HER101G-K		t <sub>rr</sub>			
	HER102G-K					
Reverse recovery time	HER103G-K			-	50	ns
	HER104G-K	I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A				
	HER105G-K	I <sub>RR</sub> =0.25A				
	HER106G-K					
	HER107G-K			-	75	ns
	HER108G-K					

#### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms



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ORDERING INFORMATION							
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING			
	A0		DO-41	3,000 / Ammo box (52mm taping)			
HER10xG-K	R0	G	DO-41	5,000 / 13" Paper reel			
(Note 1, 2)	R1		DO-41	5,000 / 13" Paper reel (Reverse)			
	B0		DO-41	1,000 / Bulk packing			

#### Notes:

- 1. "x" defines voltage from 50V (HER101G-K) to 1000V (HER108G-K)
- 2. Whole series with green compound (halogen-free)

EXAMPLE P/N								
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION				
HER101G-K A0G	HER101G-K	A0	G	Green compound				



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

2
(Y)
LN BY
ON OR HESISTIVE OR INDUCTIVE LOAD
O 25 50 75 100 125 150 175

AMBIENT TEMPERATURE (°C)

**Fig.2 Typical Junction Capacitance** 

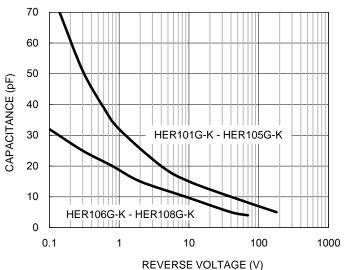


Fig.3 Typical Reverse Characteristics

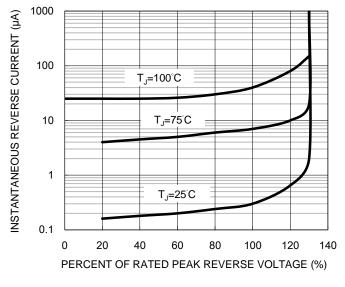
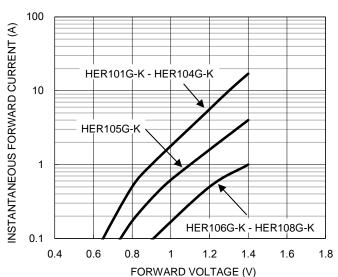


Fig.4 Typical Forward Characteristics





## **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig.5 Maximum Non-repetitive Forward Surge Current

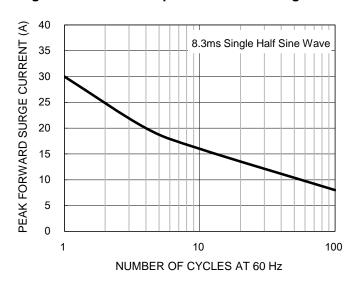
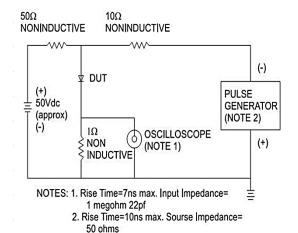
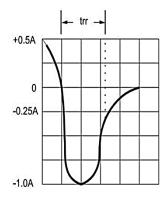


Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram



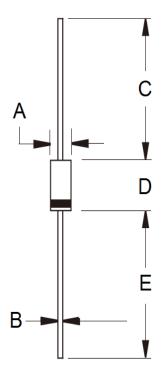


5



# **PACKAGE OUTLINE DIMENSIONS**

DO-204AL (DO-41)



DIM.	Unit (ı	mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	2.00	2.70	0.079	0.106	
В	0.71	0.86	0.028	0.034	
С	25.40	-	1.000	ı	
D	4.20	5.20	0.165	0.205	
E	25.40	-	1.000	ı	

## **MARKING DIAGRAM**



P/N = Marking Code
G = Green Compound
YWW = Date Code
F = Factory Code



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